2SC3211, 2SC3211A

Silicon NPN Triple-Diffused Junction Mesa Type

High Breakdown Voltage, High Speed Switching

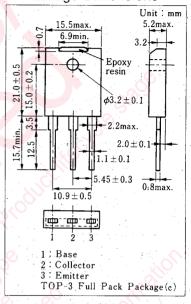
■ Features

- High speed switching
- High collector-base voltage (VcBO)
- Low collector-emitter saturation voltage (V_{CE (sat)})
- "Full Pack" package for simplified mounting on a heat sink with one screw

■ Absolute Maximum Ratings (Tc=25°C)

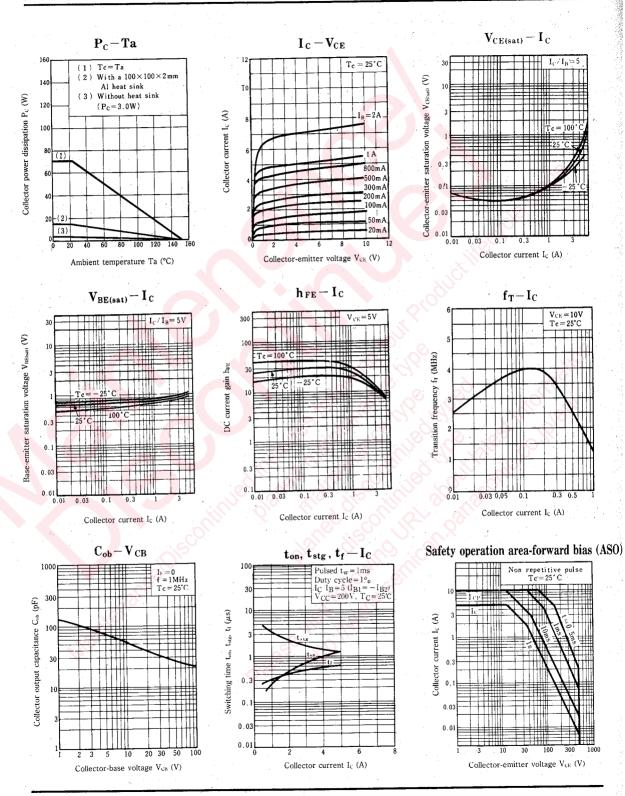
Item		Symbol	Value	Unit	
Collector- base voltage	2SC3211	V _{сво}	800	**	
	2SC3211A		900	V	
Collector-emitter voltage		$V_{\rm CEO}$	500	V	
Emitter-base voltage		$V_{\rm EBO}$	8	V	
Peak collector current		ICP	10	A	
Collector current		Ic	5	A	
Base current		I_B	3	A	
Collector power dissipation	. Tc=25℃	Pc	70		
	Ta=25℃		3	w C	
Junction temperature		T_i	150	~ °C	
Storage temperature		Tstg	$-55 \sim +150$	CC	
			A 09	· // · ()	

■ Package Dimensions

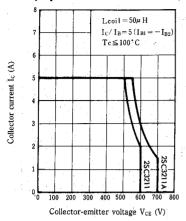


■ Electrical Characteristics (Tc=25°C)

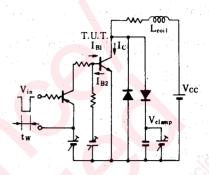
Symbol	Condition	min.	typ.	max.	Unit	
Lena	$V_{CB} = 800 \text{ V}, I_E = 0$	100				
1680	$V_{CB} = 900 \text{ V}, I_{E} = 0$			100	μΑ	
I_{EBO}	$V_{EB}=5 \text{ V}, I_C=0$		1.0	100	μΑ	
V _{CEO(sus)}	$I_C = 0.2 \text{ A}, L = 25 \text{ mH}$	500			· V	
h _{FE1}	$V_{CE} = 5 \text{ V}, I_{C} = 0.1 \text{ A}$	15				
h _{FE2}	$V_{CE}=5 \text{ V}, I_{C}=3 \text{ A}$	8				
V _{CE(sat)}	$I_C = 3 \text{ A}, I_B = 0.6 \text{ A}$			1	V	
V _{BE(sat)}	$I_{\rm C} = 3 {\rm A}, \ I_{\rm B} = 0.6 {\rm A}$,	1.5	V	
f _T	$V_{CE} = 10V, I_{C} = 0.5A, f = 1MHz$:	3		MHz	
				1		
A Lon	$I_C=3$ A			1.2	μs	
) t _{stg}	$I_{B1} = 0.6 \text{ A}, I_{B2} = -0.6 \text{ A}$			3	μs	
	V _{CC} =200 V			1		
A L				1.2	μS	
	ICBO	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	



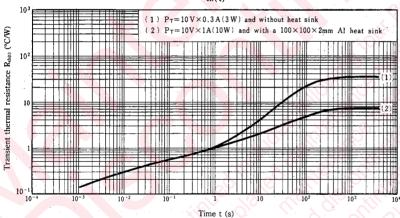
Safety operation area-reverse bias (ASO)



Measurement circuit of reverse bias ASO



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